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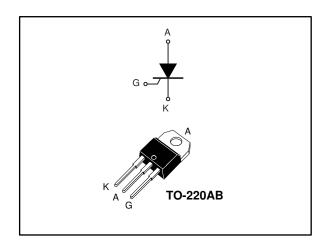


TN2010H-6T



High temperature 20 A SCRs

Datasheet - production data



Description

Packaged in a non-isolated TO-220AB, this device offers high thermal performance during operation of up to 20 A_{RMS} , thanks to a junction temperature of up to 150 °C.

The combination of noise immunity and low gate triggering current allows to design strong and compact control circuit.

Table 1: Device summary

Order code	Package	V_{DRM}/V_{RRM}	lgт	
TN2010H-6T	TO-220AB	600 V	10 mA	

Features

- High junction temperature: T_j = 150 °C
- High noise immunity $dV/dt = 400 V/\mu s$ up to 150 °C
- Gate triggering current I_{GT} = 10 mA
- Peak off-state voltage V_{DRM}/V_{RRM} = 600 V
- High turn on current rise dI/dt = 100 A/μs
- ECOPACK®2 compliant component

Applications

- Motorbike voltage regulator circuits
- Inrush current limiting circuits
- Motor control circuits and starters
- Light dimmers
- Solid state relays

Characteristics TN2010H-6T

1 Characteristics

Table 2: Absolute maximum ratings (limiting values), $T_j = 25$ °C unless otherwise specified

Symbol	Parameter			Value	Unit
I _{T(RMS)}	RMS on-state current (180 ° conduction angle)		T _c = 132 °C	20	Α
			T _c = 132 °C	12.7	
I _{T(AV)}	Average on-state current (180 ° conduction angle)		T _c = 137 °C	10	Α
	(100 conduction angle)		T _c = 140 °C	8	
	Non repetitive surge peak on-st	ate current	$t_p = 8.3 \text{ ms}$	197	
Ітѕм	(T _j initial = 25 °C)		$t_p = 10 \text{ ms}$	180	Α
l ² t	I ² t value for fusing		$t_p = 10 \text{ ms}$	162	A ² s
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, tr $\leq 100 \text{ ns}$		f = 60 Hz	100	A/μs
V _{DSM} /V _{RSM}	Non repetitive surge peak off-state voltage		t _p = 10 ms	700	٧
l _{GM}	Peak gate current	t _p = 20 μs	T _j = 150 °C	4	Α
$P_{G(AV)}$	Average gate power dissipation $T_j = 150 \text{ °C}$			1	W
V _{RGM}	Maximum peak reverse gate voltage			5	V
T _{stg}	Storage junction temperature range			-40 to +150	°C
Tj	Operating junction temperature range			-40 to +150	°C
TL	Maximum lead temperature for soldering during 10 s			260	°C

Table 3: Electrical characteristics ($T_j = 25$ °C unless otherwise specified)

Symbol	Test conditions			Value	Unit
1			Тур.	5	mA
I _{GT}	$V_D = 12 \text{ V}, R_L = 33 \Omega$		Max.	10	IIIA
V_{GT}			Max.	1.3	٧
V_{GD}	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega$ $T_j = 150 \text{ °C}$		Min.	0.1	V
Ін	I _T = 500 mA, gate open		Max.	40	mA
L	$I_G = 1.2 \times I_{GT}$		Max.	60	mA
dV/dt	$V_D = 402 \text{ V}$, gate open $T_j = 150 \text{ °C}$		Min.	400	V/µs
t _{gt}	$I_{TM} = 40 \text{ A}, V_D = 402 \text{ V}, I_G = 20 \text{ mA}, (dI_G/dt) \text{ max} = 0.2 \text{ A/}\mu\text{s}$		Тур.	1.9	μs
t_q	$I_{TM} = 40 \text{ A}, V_D = 402 \text{ V}, (d_i/dt) \text{ off} = 30 \text{ A/}\mu\text{s}, \ V_R = 25 \text{ V}, dV_D/dt = 40 \text{ V/}\mu\text{s}$ $T_j = 150 \text{ °C}$			70	μs

TN2010H-6T Characteristics

Table 4: Static characteristics

Symbol	Test conditions			Value	Unit
V _{TM}	$I_{TM} = 40 \text{ A}, t_p = 380 \ \mu s$	T _j = 25 °C	Max.	1.6	V
V _{TO}	Threshold voltage	T _j = 150 °C	Max.	0.82	V
R _D	Dynamic resistance	T _j = 150 °C	Max.	17.5	mΩ
		T _j = 25 °C		5	μΑ
I _{DRM} , I _{RRM}	$V_D = V_{DRM}, V_R = V_{RRM}$	T _j = 125 °C	Max.	2	m Λ
		T _j = 150 °C		3.9	mA

Table 5: Thermal parameters

Symbol	Parameter		Value	Unit
R _{th(j-c)}	Junction to case (DC)	Max.	1.0	°C/W
R _{th(j-a)}	Junction to ambient (DC)	Тур.	60	-0/00

Characteristics TN2010H-6T

 $I_{T(AV)}$ $\overline{(A)}$

15

1.1 Characteristics (curves)

4

2

0

Figure 1: Maximum power dissipation versus average on-state current

P(W)

18

16

14

12

10

8

6

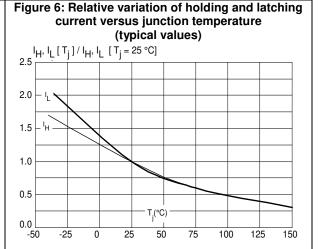
360°

10

Figure 2: Average and DC on-state current versus case temperature $I_{T(AV)}(A)$ 24 DC 22 20 18 16 14 12 $\alpha = 120^{\circ}$ 10 $\alpha = 90^{\circ}$ 8 $\alpha = 60^{\circ}$ α = 30 ° 6 4 2 T_c(°C) 0 6 75 100 125

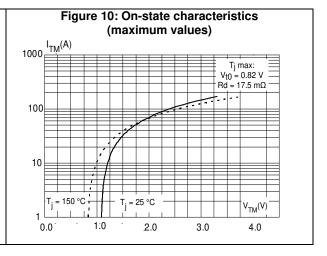
Figure 3: Average and D.C. on state current versus ambient temperature $I_{\mathsf{T}(\mathsf{AV})}(\mathsf{A})$ 3.0 2.5 DC 20 α = 180 1.5 1.0 0.5 T_a(°C) 0.0 25 50 75 100 125 150

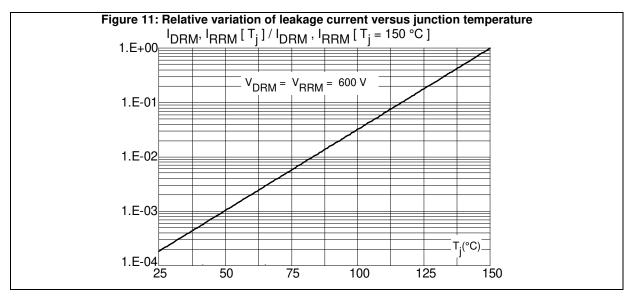
Figure 5: Relative variation of gate triggering current and gate voltage versus junction temperature (typical values) I_{GT} , V_{GT} [T_i] / I_{GT} , V_{GT} [T_i = 25 °C] 2.0 1.5 1.0 V_{GT} 0.5 T_i(°C) 0.0 75 -50 -25 0 25 50 100 125 150



TN2010H-6T Characteristics

Figure 7: Relative variation of static dV/dt immunity versus junction temperature (typical values) $dV/dt [T_j] / dV/dt [T_j = 150 °C]$ $V_D = V_R = 402 \text{ V}$ 14 Above test equipment capability 10 8 2 $T_j(^{\circ}C)$ 100 25 50 75 125





Package information TN2010H-6T

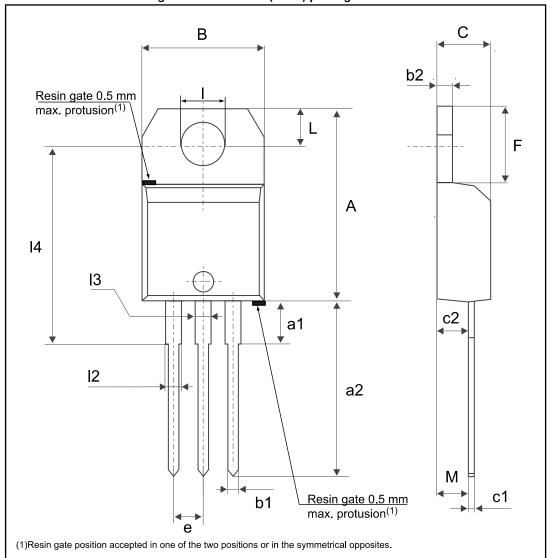
2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **www.st.com**. ECOPACK® is an ST trademark.

- Epoxy meets UL94, V0
- Lead-free, halogen-free package
- Recommended torque value (TO-220AB): 0.4 to 0.6 N.m

2.1 TO-220AB package information

Figure 12: TO-220AB (NIns.) package outline



TN2010H-6T Package information

Table 6: TO-220AB (NIns.) package mechanical data

	Dimensions					
Ref.		Millimeters			Inches ⁽¹⁾	
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	15.20		15.90	0.5984		0.6260
a1		3.75			0.1476	
a2	13.00		14.00	0.5118		0.5512
В	10.00		10.40	0.3937		0.4094
b1	0.61		0.88	0.0240		0.0346
b2	1.23		1.32	0.0484		0.0520
С	4.40		4.60	0.1732		0.1811
c1	0.49		0.70	0.0193		0.0276
c2	2.40		2.72	0.0945		0.1071
е	2.40		2.70	0.0945		0.1063
F	6.20		6.60	0.2441		0.2598
I	3.73		3.88	0.1469		0.1528
L	2.65		2.95	0.1043		0.1161
12	1.14		1.70	0.0449		0.0669
13	1.14		1.70	0.0449		0.0669
14	15.80	16.40	16.80	0.6220	0.6457	0.6614
М		2.6			0.1024	

Notes

⁽¹⁾Inch dimensions are for reference only.

Ordering information TN2010H-6T

3 Ordering information

Figure 13: Ordering information scheme

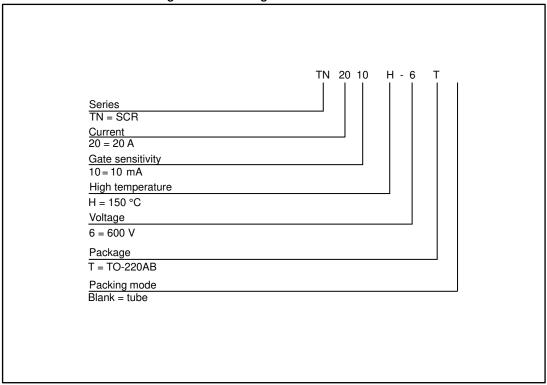


Table 7: Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
TN2010H-6T	TN2010H6	TO-220AB	2.3 g	50	Tube

4 Revision history

Table 8: Document revision history

Date	Revision	Changes
29-Aug-2017	1	Initial release.

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